

μ A747AQB Dual Operational Amplifier

Aerospace and Defense Data Sheet
Linear Products

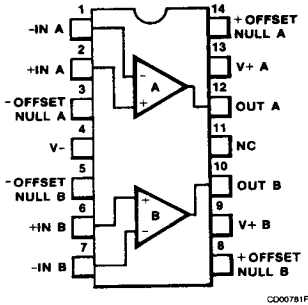
Description

The μ A747AQB is a pair of high performance monolithic operational amplifiers constructed using the Fairchild Planar Epitaxial process. They are intended for a wide range of analog applications where board space or weight are important. High common mode voltage range and absence of latch-up make the μ A747AQB ideal for use as a voltage follower. The high gain and wide range of operating voltage provide superior performance in integrator, summing amplifier, and general feedback applications.

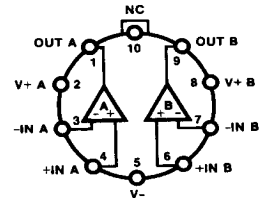
The μ A747AQB is short circuit protected and requires no external components for frequency compensation. The internal 6 dB/octave roll-off insures stability in closed loop applications.⁶

- No Frequency Compensation Required
- Short Circuit Protection
- Offset Voltage Null Capability
- Large Common Mode and Differential Voltage Ranges
- Low Power Consumption
- No Latch-Up

Connection Diagram 14-Lead DIP (Top View)

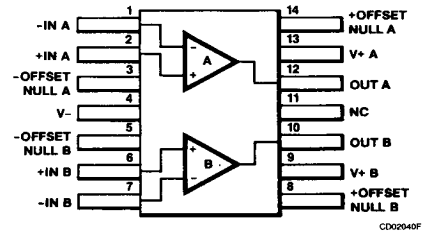


Connection Diagram 10-Lead Can (Top View)



Lead 5 connected to case.

Connection Diagram 14-Lead Flatpak (Top View)



Order Information

Part No.	Case/ Finish	Package Code Mil-M-38510, Appendix C
μ A747AFMQB	AA	F-1 14-Lead Flatpak
μ A747ADMQB	CA	D-1 14-Lead DIP
μ A747AHMQB	IC	A-2 10-Lead Can

JAN Product Available

10102	BAA	F-1 14-Lead Flatpak
10102	BAB	F-1 14-Lead Flatpak
10102	BCA	D-1 14-Lead DIP
10102	BCB	D-1 14-Lead DIP
10102	BIA	A-2 10-Lead Can
10102	BIC	A-2 10-Lead Can

Absolute Maximum Ratings

Storage Temperature Range	-65°C to +175°C
Operating Temperature Range	-55°C to +125°C
Lead Temperature (soldering, 60 s)	300°C
Internal Power Dissipation ¹²	
Can and Flatpak	350 mW
DIP	400 mW
Supply Voltage	± 22 V
Differential Input Voltage	± 30 V
Input Voltage ¹³	± 20 V
Short Circuit Duration ¹⁴	Indefinite

Processing: MIL-STD-883, Method 5004**Burn-In:** Method 1015, Condition A, PDA calculated using Method 5005, Subgroup 1**Quality Conformance Inspection:** MIL-STD-883, Method 5005**Group A Electrical Tests Subgroups:**

1. Static tests at 25°C
2. Static tests at 125°C
3. Static tests at -55°C
4. Dynamic tests at 25°C
5. Dynamic tests at 125°C
6. Dynamic tests at -55°C
9. AC tests at 25°C
10. AC tests at 125°C
11. AC tests at -55°C

Group C and D Endpoints: Group A, Subgroup 1**Notes**

1. 100% Test and Group A
2. Group A
3. Periodic tests, Group C
4. Guaranteed but not tested
5. When changes occur, FSC will make data sheet revisions available. Contact local sales representative for the latest revision.
6. For more information on device function, refer to the Fairchild Linear Data Book Commercial Section.
7. Not available on μA747AHMQB.
8. Z_i is guaranteed by I_{IB} : $Z_i = 4.0 V_T / I_{IB}$, $V_T = 26$ mV at 25°C, 34 mV at 125°C, and 19 mV at -55°C.
9. P_c is guaranteed by I_{CC} : $P_c = 40 I_{CC}$.
10. V_{IR} is guaranteed the CMR test.
11. BW is guaranteed by t_r : $BW = 0.35/t_r$.
12. Rating applies to ambient temperatures up to 125°C. Above 125°C ambient, derate linearly at 140°C/W for the Can and Flatpak and 120°C/W for the DIP.
13. For supply voltages less than ±20 V, the absolute maximum input voltage is equal to the supply voltage.
14. Short circuit may be to ground or either supply. Rating applies to 125°C case temperature or 75°C ambient temperature.

μA747AQB

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Electrical Characteristics $\pm 5.0 \text{ V} \leq V_{CC} \leq \pm 20 \text{ V}$, unless otherwise specified.

Symbol	Characteristic		Condition	Min	Max	Unit	Note	Subgrp
V_{IO}	Input Offset Voltage		$R_S = 50 \text{ k}\Omega$, $V_{CM} = 0 \text{ V}$		3.0	mV	1	1
					4.0	mV	1	2,3
$\Delta V_{IO}/\Delta T$	Input Offset Voltage Temperature Sensitivity		$25^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		15	$\mu\text{V}/^\circ\text{C}$	4	2
			$-55^\circ\text{C} \leq T_A \leq +25^\circ\text{C}$		15	$\mu\text{V}/^\circ\text{C}$	4	3
$V_{IO \text{ adj}}$	Input Offset Voltage Adjustment Range ⁷		$V_{CC} = \pm 20 \text{ V}$	5.0		mV	1	1,2,3
I_{IO}	Input Offset Current		$V_{CM} = 0 \text{ V}$		30	nA	1	1
					70	nA	1	2,3
$\Delta I_{IO}/\Delta T$	Input Offset Current Temperature Sensitivity		$25^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		0.2	$\text{nA}/^\circ\text{C}$	4	2
			$-55^\circ\text{C} \leq T_A \leq +25^\circ\text{C}$		0.5	$\text{nA}/^\circ\text{C}$	4	3
I_{IB}	Input Bias Current		$V_{CM} = 0 \text{ V}$		80	nA	1	1
					210	nA	1	2,3
Z_i	Input Impedance ⁸		$V_{CC} = \pm 20 \text{ V}$	1.0		$\text{M}\Omega$	1	1
				0.5		$\text{M}\Omega$	1	2
I_{CC}	Supply Current (Total)		$V_{CC} = \pm 20 \text{ V}$		7.50	mA	1	1
					6.75	mA	1	2
					8.25	mA	1	3
P_c	Power Consumption (Total) ⁹		$V_{CC} = \pm 20 \text{ V}$		300	mW	1	1
					270	mW	1	2
					330	mW	1	3
CMR	Common Mode Rejection		$V_{CC} = \pm 20 \text{ V}$, $V_{CM} = \pm 15 \text{ V}$, $R_S = 50 \Omega$	80		dB	1	1,2,3
V_{IR}	Input Voltage Range ¹⁰			± 15		V	1	1,2,3
PSRR	Power Supply Rejection Ratio		$V_+ = 10 \text{ V}$, $V_- = -20 \text{ V}$ to $V_+ = 20 \text{ V}$, $V_- = -10 \text{ V}$, $R_S = 50 \Omega$		50	$\mu\text{V}/\text{V}$	1	1
					100	$\mu\text{V}/\text{V}$	1	2,3
I_{OS}	Output Short Circuit Current				60	mA	1	1,2,3
A_{VS}	Large Signal Voltage Gain		$V_{CC} = \pm 20 \text{ V}$, $V_O = \pm 15 \text{ V}$, $R_L = 2.0 \text{ k}\Omega$		50	V/mV	1	4
					32	V/mV	1	5,6
			$V_{CC} = \pm 5 \text{ V}$, $V_O = \pm 2 \text{ V}$, $R_L = 2.0 \text{ k}\Omega$		10	V/mV	1	4,5,6
V_{OP}	Output Voltage Swing		$V_{CC} = \pm 20 \text{ V}$	$R_L = 10 \text{ k}\Omega$	± 16	V	1	4,5,6
				$R_L = 2.0 \text{ k}\Omega$	± 15	V	1	4,5,6
$TR(t_r)$	Transient Response	Rise Time	$V_{CC} = \pm 20 \text{ V}$, $V_I = 50 \text{ mV}$, $R_L = 2.0 \text{ k}\Omega$, $C_L = 100 \text{ pF}$, $A_V = 1.0$		800	ns	3	9, 10, 11
$TR(O_s)$		Overshoot			25	%	3	9, 10, 11
BW	Bandwidth ¹¹			0.437		MHz	3	9, 10, 11

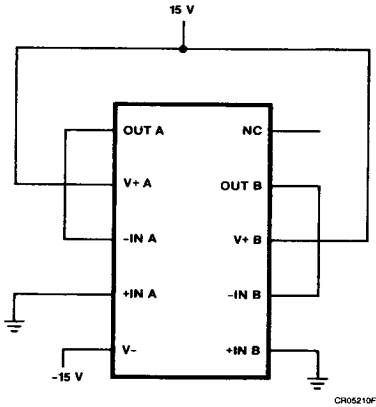
μA747AQB (Cont.)

Electrical Characteristics $\pm 5.0 \text{ V} \leq V_{CC} \leq \pm 20 \text{ V}$, unless otherwise specified.

Symbol	Characteristic	Condition	Min	Max	Unit	Note	Subgrp
SR	Slew Rate	$V_{CC} = \pm 20 \text{ V}$, $R_L = 2.0 \text{ k}\Omega$, $A_V = 1.0$	0.3		$\text{V}/\mu\text{s}$	3	9, 10, 11
CS	Channel Separation	$V_{CC} = \pm 20 \text{ V}$	100		dB	1	9, 10, 11
N_i (BB)	Noise Broadband	$V_{CC} = \pm 20 \text{ V}$, $\text{BW} = 5.0 \text{ kHz}$		15	μV_{rms}	4	9
N_i (PC)	Noise Popcorn	$V_{CC} = \pm 20 \text{ V}$, $\text{BW} = 5.0 \text{ kHz}$		40	μV_{pk}	4	9

Primary Burn-In Circuit

(38510/10102 may be used by FSC as an alternate)



Equivalent Circuit

